

mos integrated circuit $\mu PD178F098$

8-BIT SINGLE-CHIP MICROCONTROLLER

DESCRIPTION

The μ PD178F098 is a flash memory model of the μ PD178076, 178078, 178096, and 178098, and is provided with a flash memory to/from which data can be written/erased with the microcontroller mounted on a printed circuit board.

For the detailed functional description, refer to the following User's Manuals:

 μ PD178078, 178098 Subseries User's Manual: U12790E 78K/0 Series User's Manual - Instruction : U12326E

FEATURES

- · Serial interface (UART mode)
- IEBus[™] controller
- Pin-compatible with mask ROM models (except VPP pin)
- Flash memory: 60K bytes^{Note}
- Internal high-speed RAM: 1024 bytes
- Internal extension RAM: 2048 bytes^{Note}
- · Buffer RAM: 32 bytes
- Operable at same supply voltage as mask ROM models (VDD = 4.5 to 5.5 V during PLL operation)

Note The capacities of the flash memory and internal extension RAM can be changed using the memory size select register (IMS) and internal extension RAM size select register (IXS).

Remark For the differences between the flash memory model and mask ROM models, refer to 1. DIFFERENCES BETWEEN μ PD178F098 AND MASK ROM MODELS.

The electrical specifications (such as supply current) in the μ PD178F098 differ from those of the mask ROM models. Confirm these differences before mass-producing any application set.

APPLICATION FIELD

Car stereos

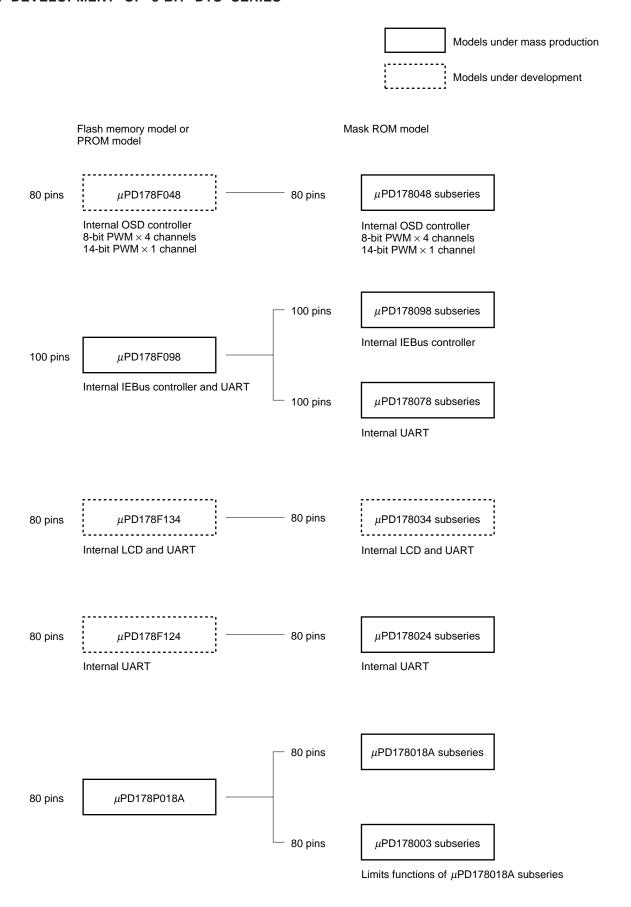
ORDERING INFORMATION

Part Number	Package
μPD178F098GF-3BA	100-pin plastic QFP (14 × 20)

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★ DEVELOPMENT OF 8-BIT DTS SERIES





FUNCTIONAL OUTLINE

(1/2)

	Item	Functions			
Internal	Flash memory	60K bytes			
memory	High-speed RAM	1024 bytes			
	Buffer RAM	32 bytes			
	Extension RAM	2048 bytes			
General-pur	pose register	8 bits × 32 registers (8 bits × 8 registers × 4 banks)			
Minimum ins	struction execution	• 0.32 μ s/0.64 μ s/1.27 μ s/2.54 μ s/5.08 μ s (with crystal resonator of fx = 6.3 MHz)			
time		• 0.44 μ s/0.89 μ s/1.78 μ s/3.56 μ s/7.11 μ s (with crystal resonator of fx = 4.5 MHz)Note 1			
Instruction set • 16-bit operation • Multiplication/division (8 bits × 8 bits, 16 bits ÷ 8 bits) • Bit manipulation (set, reset, test Boolean operation) • BCD adjustment, etc.					
I/O port		Total : 80 pins			
		CMOS input : 8 pins			
		CMOS I/O : 64 pins			
		N-ch open-drain output: 8 pins			
A/D converte	er	8-bit resolution × 8 channels			
Serial interfa	ace	• 3-wire/SBI/2-wire/I ² C bus ^{Note 2} mode selectable : 1 channel			
		• 3-wire mode : 1 channel			
		3-wire mode (with automatic transmit/receive function of up to 32 bytes): 1 channel UART mode : 1 channel			
IEBus contro	aller	Provided			
Timer	Jilei	Basic timer (timer carry FF (10 Hz)) : 1 channel			
riiilei		• 16-bit timer/event counter : 1 channel			
		8-bit timer/event counter : 2 channels			
		Watchdog timer : 1 channel			
Buzzer outp	ut	BEEP0 pin: 1 kHz, 1.5 kHz, 3 kHz, 4 kHz			
		BUZ pin: 0.77 kHz, 1.54 kHz, 3.08 kHz, 6.15 kHz (with crystal resonator of fx = 6.3 MHz)			
Vectored	Maskable	Internal : 15, External: 8			
interrupt	Non-maskable	Internal: 1			
source	Software	1			
PLL	Division mode	2 types			
frequency		Direct division mode (VCOL pin)			
synthesizer		Pulse swallow mode (VCOL and VCOH pins)			
	Reference frequency	Seven types selectable in software (1, 3, 9, 10, 12.5, 25, 50 kHz)			
	Charge pump	Error out output: 2 pins			
	Phase comparator	Unlock detectable in software			

- **Notes 1.** When using the IEBus controller, the 4.5-MHz crystal resonator cannot be used. Use the 6.3-MHz crystal resonator.
 - 2. When the I²C bus mode is used (including when the mode is implemented in software without using the peripheral hardware), consult NEC when ordering a mask.

(2/2)

Item	Functions			
Frequency counter	Frequency measurement			
	AMIFC pin: For 450-kHz counting			
	FMIFC pin: For 450-kHz/10.7-MHz counting			
Standby function	• HALT mode			
	• STOP mode			
Reset	Reset by RESET pin			
	Internal reset by watchdog timer			
	Reset by power-ON clear circuit			
	Detection of less than 4.5 V ^{Note} (Reset does not occur, however.)			
	Detection of less than 3.5 V ^{Note} (during CPU operation)			
	Detection of less than 2.3 V ^{Note} (in STOP mode)			
Supply voltage	• V _{DD} = 4.5 to 5.5 V (during CPU, PLL operation)			
	• V _{DD} = 3.5 to 5.5 V (during CPU operation)			
Package	100-pin plastic QFP (14 \times 20)			

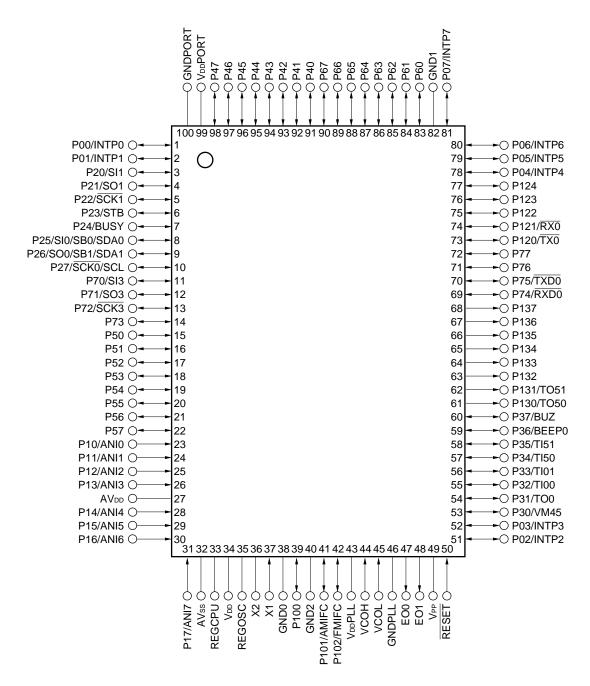
Note These voltages are the maximum values. In practice, the chip may be reset at voltages lower than these.



PIN CONFIGURATION (Top View)

 \bullet 100-pin plastic QFP (14 \times 20)

μPD178F098GF-3BA



Cautions 1. Directly connect the VPP pin to GND0, GND1, or GND2 in normal operating mode.

- 2. Keep the voltage at AVDD, VDDPORT, and VDDPLL same as that at the VDD pin.
- 3. Keep the voltage at AVss, GNDPORT, and GNDPLL same as that at GND0, GND1, or GND2.
- 4. Connect each of the REGOSC and REGCPU pins to GND via a 0.1- μ F capacitor.

μ**PD178F098**

NEC

P	in	N	2	m	_
	m	IN	а	ш	е

GNDPLL

: PLL ground

AMIFC : AM intermediate frequency counter REGOSC : Regulator for oscillation circuit

input RESET : Reset input

BEEP0, BUZ : Buzzer output SCL : Serial clock input/output EO0, EO1 : Error out output SDA0, SDA1 : Serial data input/output

FMIFC : FM intermediate frequency counter SI0, SI1, SI3 : Serial data input

input SO0, SO1, SO3 : Serial data output

GND0-GND2 : Ground TI00, TI01 : 16-bit timer capture trigger input

STB

: Strobe output

INTP0-INTP7 : Interrupt input TI50, TI51 : 8-bit timer clock input P00-P07 : Port 0 TO0 : 16-bit timer output P10-P17 : Port 1 TO50, TO51 : 8-bit timer output

P20-P27 : Port 2 TXD0 : UART0 serial data output P30-P37 : Port 3 TX0 : IEBus serial data output P40-P47 : Port 4 VCOL, VCOH : Local oscillation input P50-P57 : Port 5 **VDDPORT** : Port power supply P60-P67 : Port 6 **VDDPLL** : PLL power supply

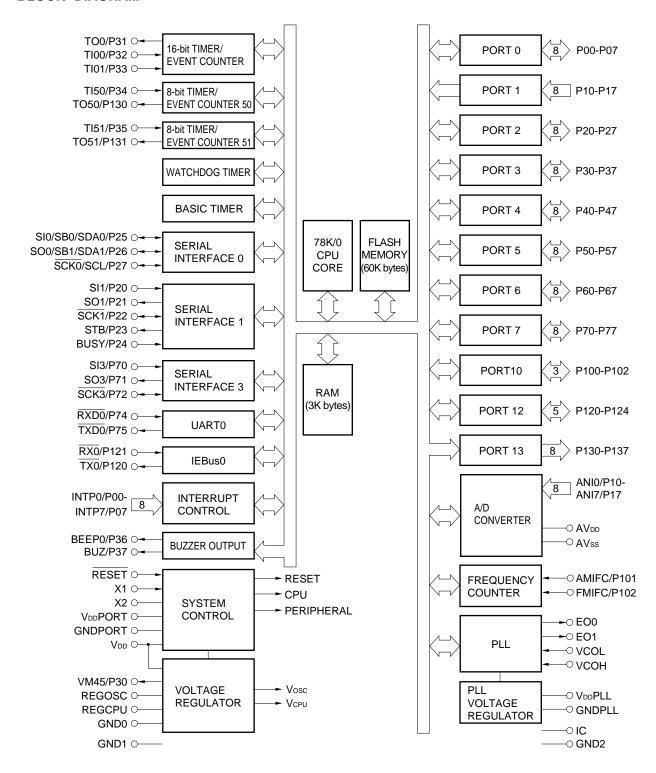
P70-P77 : Port 7 V_{DD} : Power supply

P100-P102 : Port 10 VM45 : $V_{DD} = 4.5 \text{ V}$ monitor output P120-P124 : Port 12 V_{PP} : Programming power supply

P130-P137 : Port 13 X1, X2 : Crystal resonator REGCPU : Regulator for CPU power supply



BLOCK DIAGRAM





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1. DIFFERENCES BETWEEN μ PD178F098 AND MASK ROM MODELS

The μ PD178F098 is provided with a flash memory to/from which data can be written/erased with the device mounted on a printed circuit board. The differences between the flash memory model (μ PD178F098) and mask ROM models (μ PD178076, 178078, 178096, and 178098) are shown in Table 1-1.

Table 1-1. Differences between μ PD178F098 and Mask ROM Models

Item		μPD178F098	μPD178076, 178078	μPD178096, 178098	
Internal memory ROM structure		Flash memory Mask ROM			
ROM capacity		60K bytes	μPD178076: 48K bytes	μPD178096: 48K bytes	
			μPD178078: 60K bytes	μPD178098: 60K bytes	
	External	2048 bytes	μPD178076: 1024 bytes	μPD178096: 1024 bytes	
	extension RAM		μPD178078: 2048 bytes	μPD178098: 2048 bytes	
Internal ROM capa	city selected by	Equivalent to mask ROM	μPD178076: CCH	μPD178096: CCH	
memory size select	register (IMS)	model	μPD178078: CFH	μPD178098: CFH	
Internal extension F	RAM capacity	Equivalent to mask ROM	μPD178076: 0AH	μPD178096: 0AH	
selected by interna	l extension RAM	model	μPD178078: 08H	μPD178098: 08H	
size select register	(IXS)				
Serial interface		4 channels	3 channels		
		3-wire/SBI/2-wire/I ² C bus	• 3-wire/SBI/2-wire/I ² C bus		
		3-wire (with automatic tra	mode selectable		
		• 3-wire		3-wire (with automatic	
		• UART		transmit/receive function)	
				• 3-wire	
IEBus controller		Provided	Not provided	Provided	
Interrupt source		24	22	21	
IC pin		Not provided	Provided		
V _{PP} pin		Provided Not provided			
Electrical specificat	ions and	See the relevant data sheet			
recommended sold	ering conditions				

Caution The noise resistance and noise radiation differ between flash memory versions and mask ROM versions. When considering the replacement of flash memory versions with mask ROM versions in the process from trial manufacturing to mass production, adequate evaluation should be carried out using CS products (not ES products) of mask ROM versions.

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2. PIN FUNCTION LIST

2.1 Port Pins (1/2)

Pin Name	I/O	Function	At Reset	Shared by:
P00-P07	I/O	Port 0. 8-bit I/O port. Can be set in input or output mode in 1-bit units.	Input	INTP0-INTP7
P10-P17	Input	Port 1. 8-bit input port.	Input	ANI0-ANI7
P20	I/O	Port 2.	Input	SI1
P21	_	8-bit I/O port.		SO1
P22	7	Can be set in input or output mode in 1-bit units.		SCK1
P23				STB
P24				BUSY
P25	1			SI0/SB0/SDA0
P26				SO0/SB1/SDA1
P27				SCK0/SCL
P30	I/O	Port 3.	Input	VM45
P31		8-bit I/O port.		TO0
P32		Can be set in input or output mode in 1-bit units.		T100
P33				TI01
P34	_			TI50
P35	_			TI51
P36				BEEP0
P37				BUZ
P40-47	I/O	Port 4. 8-bit I/O port. Can be set in input or output mode in 1-bit units.	Input	-
P50-P57	I/O	Port 5. 8-bit I/O port. Can be set in input or output mode in 1-bit units.	Input	-
P60-P67	I/O	Port 6. 8-bit I/O port. Can be set in input or output mode in 1-bit units.	Input	-
P70	I/O	Port 7.	Input	SI3
P71	1	8-bit I/O port.		SO3
P72	1	Can be set in input or output mode in 1-bit units.		SCK3
P73	1			_
P74	1			RXD0
P75	1			TXD0
P76, P77	1			_



2.1 Port Pins (2/2)

Pin Name	I/O	Function	At Reset	Shared by:
P100	I/O	Port 10.	Input	_
P101		3-bit I/O port.		AMIFC
P102		Can be set in input or output mode in 1-bit units.		FMIFC
P120	I/O	Port 12. Input T		TX0
P121		5-bit I/O port.		RX0
P122-P124		Can be set in input or output mode in 1-bit units.		_
P130	Output	Port 13.	Low-level	TO50
P131		8-bit output port.	output	TO51
P132-P137		N-ch open-drain output port (15 V withstand)		_

2.2 Pins Other Than Port Pins (1/2)

Pin Name	I/O	Function		At Reset	Shared by:
INTP0-INTP7	Input	External maskable interrupt input	Input	P00-P07	
		(rising edge, falling edge, or both			
		can be specified.			
SI0	Input	Serial data input to serial interfac	e.	Input	P25/SB0/SDA0
SI1					P20
SI3					P70
SO0	Output	Serial data output from serial inte	rface.	Input	P26/SB1/SDA1
SO1					P21
SO3					P71
SB0	I/O	Serial data input/output to/from	N-ch open drain I/O	Input	P25/SI0/SDA0
SB1		serial interface.			P26/SO0/SDA1
SDA0					P25/SI0/SB0
SDA1					P26/SO0/SB1
SCK0	I/O	Serial clock input/output to/from s	serial interface.	Input	P27/SCL
SCK1					P22
SCK3					P72
SCL			N-ch open drain I/O	_	P27/SCK0
STB	Output	Strobe output for serial interface	automatic transmission/	Input	P23
		reception.			
BUSY	Input	Busy input for serial interface aut	omatic transmission/	Input	P24
		reception.			
VW45	Output	V _{DD} = 4.5 V monitor output		Input	P30
TI00	Input	External count clock input to 16-b	oit timer (TM0).	Input	P32
TI01					P33
TI50	Input	External count clock input to 8-bit	t timer (TM50).	Input	P34
TI51		External count clock input to 8-bit	t timer (TM51).		P35
TO0	Output	16-bit timer (TM0) output.		Input	P31
TO50		8-bit timer (TM50) output.		Low-level	P130
TO51		8-bit timer (TM51) output.		output	P131
BEEP0	Output	Buzzer output.		Input	P36
BUZ					P37

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2.2 Pins Other Than Port Pins (2/2)

Pin Name	I/O	Function	At Reset	Shared by:
ANI0-ANI7	Input	Analog input to A/D converter. Input P		P10-P17
E00, E01	Output	Error out output from charge pump of PLL frequency –		_
		synthesizer.		
VCOL	Input	Inputs local oscillation frequency of PLL (in HF and MF	-	_
		modes).		
VCOH	Input	Inputs local oscillation frequency of PLL (in VHF mode).	-	_
AMIFC	Input	Input to AM intermediate frequency counter.	Input	P101
FMIFC	Input	Input to FM intermediate frequency or AM intermediate	Input	P102
		frequency counter.		
RXD0	Input	Serial data input to asynchronous serial interface (UART0).	Input	P74
TXD0	Output	Serial data output from asynchronous serial interface	Input	P75
		(UART0).		
TX0	Output	IEBus controller data output.	Input	P120
RX0	Input	IEBus controller data input.	Input	P121
RESET	Input	System reset input.	_	
X1	Input	Connection of crystal resonator for system clock oscillation.	_	_
X2	_		_	-
REGOSC	-	Regulator for oscillation circuit. Connect this pin to GND via		_
		0.1 - μ F capacitor.		
REGCPU	_	Regulator for CPU power supply. Connect this pin to GND	_	_
		via 0.1 - μ F capacitor.		
V _{DD}	-	Positive power supply.	_	_
GND0-GND2	-	Ground.	_	_
VDDPORT	-	Port power supply.	_	_
GNDPORT	_	Port ground.	_	_
AV _{DD}	-	A/D converter positive power supply. Keep voltage at this	_	_
		pin same as that at V _{DD} 0.		
AVss	-	A/D converter ground. Keep voltage at this pin same as	_	_
		that at GND0 through GND2.		
V _{DD} PLL Note	-	PLL positive power supply.	y .	
GNDPLL ^{Note}	_	PLL ground.	_	_
V _{PP}	_			_
		Directly connect this pin to GND0, GND1, or GND2 in		
		normal operating mode.		

Note Connect a capacitor of about 1000 pF between the VDDPLL and GNDPLL pins.



2.3 I/O Circuits of Pins and Recommended Connections of Unused Pins

Table 2-1 shows the types of the I/O circuits of the respective pins and the recommended connections of the pins when they are not used.

For the configuration of the I/O circuit of each pin, refer to Figure 2-1.

Table 2-1. I/O Circuit Type of Each Pin (1/2)

Pin Name	I/O Circuit Type	I/O	Recommended Connection of Unused Pin
P00/INTP0-P07/INTP7	8	I/O	Input: Connect each of them to V _{DD} , V _{DD} PORT, GND0 to GND2, or GNDPORT via resistor. Output: Leave open.
P10/ANI0-P17/ANI7	25	Input	Connect these pins to VDD, VDDPORT, GND0 to GND2 or GNDPORT.
P20/SI1	5-K	I/O	Input: Connect each of them to VDD, VDDPORT, GND0 to
P21/SO1	5		GND2, or GNDPORT via resistor.
P22/SCK1	5-K		Output: Leave open.
P23/STB	5		
P24/BUSY	5-K		
P25/SI0/SB0/SDA0	10-D		
P26/SO0/SB1/SDA1			
P27/SCK0/SCL			
P30/VM45	5		
P31/TO0			
P32/TI00	5-K		
P33/TI01			
P34/TI50			
P35/TI51			
P36/BEEP0	5		
P37/BUZ			
P40-P47			
P50-P57			
P60-P67			
P70/SI3	5-K		
P71/SO3	5		
P72/SCK3	5-K		
P73	5		
P74/RXD0	5-K		
P75/TXD0	5		
P76, P77			
P100			
P101/AMIFC			
P102/FMIFC			
P120/TX0			
P121/RX0	5-K		
P122-P124	5		



Table 2-1. I/O Circuit Type of Each Pin (2/2)

Pin Name	I/O Circuit Type	I/O	Recommended Connection of Unused Pin
P130/TO50	19	Output	Open these pins.
P131/TO51			
P132-P137			
EO0	DTS-EO1		
EO1			
VCOL, VCOH	DTS-AMP2	Input	Disable PLL in software and select pull-down.
REGOSC, REGCPU	_	_	Connect these pins to GND0, GND1, or GND2 via $0.1-\mu F$ capacitor.
RESET	2	Input	-
AVDD	_	_	Connect this pin to VDD or VDDPORT.
AVss			Directly connect these pins to GND0 to GND2, or GNDPORT.
VPP			

Type 2 Type 5 data O IN/OUT IN O output disable input Schmitt trigger input with hysteresis characteristics enable Type 5-K Type 8 data data -O IN/OUT -○ IN/OUT output N-ch disable output disable input enable Type 10-D Type 19 data -○ OUT O IN/OUT open drain N-ch output disable input enable

Figure 2-1. I/O Circuits of Respective Pins (1/2)

Remark VDD and GND are the positive power supply and ground pins for all port pins. Take VDD and GND as VDDPORT and GNDPORT.

μPD178F098

Type DTS-EO1

Comparator
Weef (Threshold voltage)

IN

UP
N-ch
WGNDPLL

Type DTS-AMP

VonPLL

VonPLL

VonPLL

VonPLL

VonPLL

VonPLL

VonPLL

VonPLL

Figure 2-1. I/O Circuits of Respective Pins (2/2)

 $\textbf{Note} \quad \text{This switch is selectable in software only for the VCOL and VCOH pins.}$

Note

GNDPLL

Remark VDD and GND are the positive power supply and ground pins for all port pins. Take VDD and GND as VDDPORT and GNDPORT.

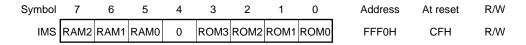
3. MEMORY SIZE SELECT REGISTER (IMS)

The internal memory capacity of the μ PD178F098 can be changed using the memory size select register (IMS). By using this register, the memory of the μ PD178F098 can be mapped in the same manner as a mask ROM model with a different internal memory capacity.

Use an 8-bit memory manipulation instruction to set the IMS.

This register is set to CFH at reset.

Figure 3-1. Format of Memory Size Select Register (IMS)



RAM2	RAM1	RAM0	Selects internal high-speed RAM capacity
1	1	0	1024 bytes
Others			Setting prohibited

RAM3	RAM2	RAM1	RAM0	Selects internal ROM capacity
1	1	0	0	48K bytes
1	1	1	1	60K bytes
Others				Setting prohibited

Table 3-1 shows the setting of IMS to perform the same memory mapping as that of a mask ROM model.

Table 3-1. Setting of Memory Size Select Register

Targeted Model	Setting of IMS
μPD178076, 178096	ССН
μPD178078, 178098	CFH



4. INTERNAL EXTENSION RAM SIZE SELECT REGISTER (IXS)

The internal extention RAM capacity of the μ PD178F098 can be changed using the internal extention RAM size select register (IXS). By using this register, the memory of the μ PD178F098 can be mapped in the same manner as a mask ROM model with a different internal extention RAM capacity.

Use an 8-bit memory manipulation instruction to set the IXS.

This register is set to 0CH at reset.

Figure 4-1. Format of Internal Extension RAM Size Select Register (IXS)

Symbol	7	6	5	4	3	2	1	0	Address	At reset	R/W
IXS	0	0	0	IXRAM4	IXRAM3	IXRAM2	IXRAM1	IXRAM0	FFF4H	0CH	R/W

IXRAM4	IXRAM3	IXRAM2	IXRAM1	IXRAM0	Selects internal extension RAM capacity
0	1	0	0	0	2048 bytes
0	1	0	1	0	1024 bytes
Others	3				Setting prohibited

Table 4-1 shows the setting of IXS to perform the same memory mapping as that of a mask ROM model.

Table 4-1. Setting of Internal RAM Size Select Register

Targeted Model	Setting of IXS
μPD178076, 178096	0AH
μPD178078, 178098	08H



5. INTERRUPT FUNCTION

The μ PD178F098 has the following three types and 24 sources of interrupts:

Non-maskable : 1^{Note}
 Maskable : 23^{Note}
 Software : 1

Note Two types of watchdog interrupt sources (INTWDT), non-maskable and maskable, are available, and either of them can be selected.

Table 5-1. Interrupt Sources (1/2)

Interrupt Type	Default Priority ^{Note 1}	Name	Interrupt Source Trigger	Internal/ External	Vector Table Address	Basic Configuration Type ^{Note 2}
Non-maskable	-	INTWDT	Overflow of watchdog timer (when watchdog timer mode 1 is selected)	Internal	0004H	(A)
Maskable	0	INTWDT	Overflow of watchdog timer (when interval timer mode is selected)			(B)
	1	INTP0	Pin input edge detection	External	0006H	(C)
	2	INTP1			H8000	
	3	INTP2			000AH	
	4	INTP3			000CH	
	5	INTP4			000EH	
	6	INTP5			0010H	
	7	INTP6			0012H	
	8	INTP7			0014H	
	9	INTCSI0	End of transfer by serial interface 0	Internal	0016H	(B)
	10	INTCSI1	End of transfer by serial interface 1		0018H	
	11	INTCSI3	End of transfer by serial interface 3		001AH	
	12	INTTM50	Generation of coincidence signal of 8-bit timer/event counter 50		001CH	
	13	INTTM51	Generation of coincidence signal of 8-bit timer/event counter 51		001EH	
	14	INTSER0	Reception error of serial interface UART0		0020H	
	15	INTSR0	End of reception by serial interface UART0		0022H	
	16	INTST0	End of transmission by serial interface UART0		0024H	
	17	INTBTM0	Generation of coincidence signal of basic timer		0026H	

Notes 1. If two or more maskable interrupts occur at the same time, they are acknowledged or kept pending according to their default priorities. The default priority 0 is the highest, while 22 is the lowest.

2. (A) to (E) under the heading Basic Configuration Type corresponds to (A) to (E) in Figure 5-1.

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Table 5-1. Interrupt Sources (2/2)

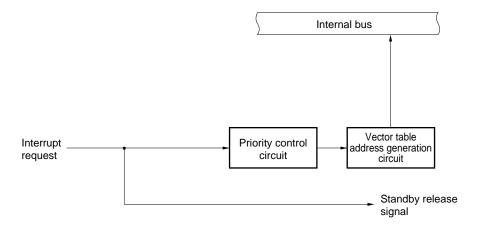
Interrupt Type	Default Priority ^{Note 1}	Interrupt Source Name Trigger		Internal/ External	Vector Table Address	Basic Configuration TypeNote 2
Maskable	18	INTTM00	Generation of signal indicating coincidence between 16-bit timer counter (TM0) and capture/compare register (CR00) (when CR00 is used as compare register)	Internal	0028H	(B)
			Detection of input edge of TI00/P32 pin (when CR00 is used as capture register)	External		(D)
	19	INTTM01	Generation of signal indicating coincidence between 16-bit timer counter (TM0) and capture/compare register (CR01) (when CR01 is used as compare register)	Internal	002AH	(B)
			Detection of input edge of TI01/P33 pin (when CR01 is used as capture register)	External		(D)
	20	INTIE1	IEBus0 data access request	Internal	002CH	(B)
	21	INTIE2	IEBus0 communication error and start/end of communication		002EH	
	22	INTAD	End of conversion by A/D converter AD1		0030H	(B)
Software	-	BRK	Execution of BRK instruction	_	003EH	(E)

Notes 1. If two or more maskable interrupts occur at the same time, they are acknowledged or kept pending according to their default priorities. The default priority 0 is the highest, while 22 is the lowest.

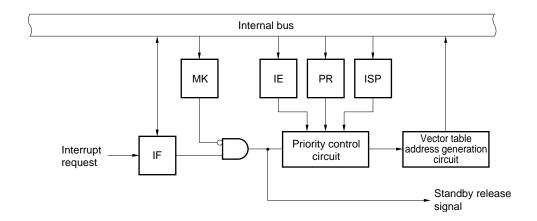
2. (A) to (E) under the heading Basic Configuration Type corresponds to (A) to (E) in Figure 5-1.

Figure 5-1. Basic Configuration of Interrupt Function (1/2)

(A) Internal non-maskable interrupt



(B) Internal maskable interrupt



(C) External maskable interrupt (INTP0 through INTP7)

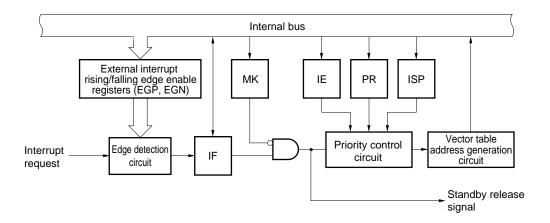
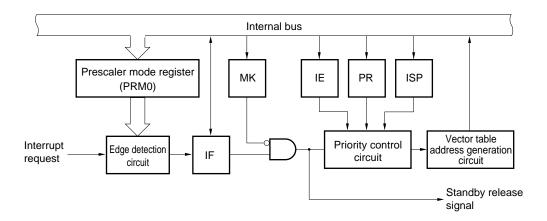


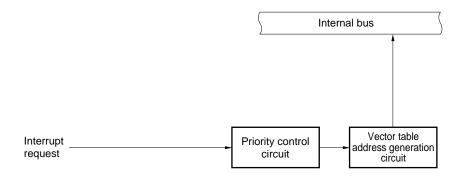


Figure 5-1. Basic Configuration of Interrupt Function (2/2)

(D) External maskable interrupts (INTTM00, INTTM01)



(E) Software interrupt



Remark IF: Interrupt request flag

IE: Interrupt enable flag
ISP: In-service priority flag
MK: Interrupt mask flag
PR: Priority specification flag

6. FLASH MEMORY PROGRAMMING

The program memory provided in the μ PD178F098 is flash memory.

The flash memory can be written on-board, i.e., with the μPD178F098 mounted on the target system.

To do so, connect a dedicated flash writer (Flashpro III (Part number FL-PR3, PG-FP3)) to the host machine and target system.

Remark FL-PR3 is a product of Naito Densei Machida Mfg. Co., Ltd.

6.1 Selecting Communication Mode

The flash memory is written by using Flashpro III and by means of serial communication. Select a communication mode from those listed in Table 6-1. To select a communication mode, the format shown in Figure 6-1 is used. Each communication mode is selected depending on the number of VPP pulses shown in Table 6-1.

 Communication Mode
 Number of Channels
 Pins Used
 Number of VPP Pulses

 3-wire serial I/O (SIO3)
 1
 SI3/P70 SO3/P71 SCK3/P72
 0

 UARTO
 1
 RXD0/P74 TXD0/P75
 8

Table 6-1. Communication Modes

Caution Be sure to select a communication mode by the number of VPP pulses shown in Table 6-1.

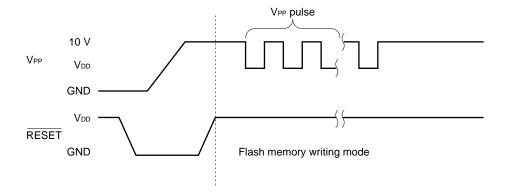


Figure 6-1. Communication Mode Selection Format



6.2 Flash Memory Programming Function

An operation such as writing the flash memory is performed when a command or data is transmitted/received in the selected communication mode. The major flash memory programming functions are listed in Table 6-2.

Table 6-2. Major Flash Memory Programming Functions

Function	Description
Batch erase	Erases all memory contents.
Batch blank check	Checks erased status of entire memory.
Data write	Writes data to flash memory starting from write start address and based on number of data (bytes) to be written).
Batch verify	Compares all contents of memory with input data.

6.3 Connecting Flashpro III

Connection with Flashpro III differs depending on the communication mode (3-wire serial I/O or UART0). Figures 6-2 and 6-3 show the connection in the respective modes.

Figure 6-2. Connection of Flashpro III in 3-Wire Serial I/O Mode $\,$

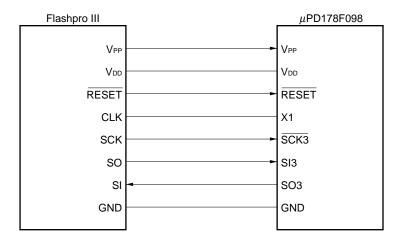
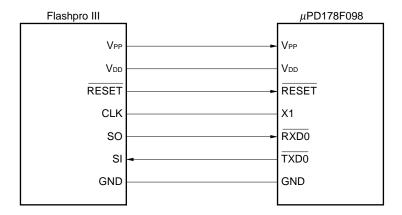


Figure 6-3. Connection of Flashpro III in UARTO Mode





* 7. ELECTRICAL SPECIFICATIONS

Absolute Maximum Ratings (T_A = 25°C)

Parameter	Symbol		Conditions		Rating	Unit
Supply voltage					-0.3 to +6.0	V
	VDDPORT				-0.3 to V _{DD} + 0.3 ^{Note 1}	V
	AVDD				-0.3 to V _{DD} + 0.3 ^{Note 1}	V
	VDDPLL				-0.3 to V _{DD} + 0.3 ^{Note 1}	V
	VPP				-0.3 to +10.5	V
Input voltage	Vı				-0.3 to V _{DD} + 0.3	V
Output voltage	Vo	Excluding P130	to P137		-0.3 to V _{DD} + 0.3	V
Output breakdown	V _{BDS}	P130-P137	N-ch open drain		16	V
voltage						
Analog input voltage	Van	P10-P17	Analog input pin		-0.3 to V _{DD} + 0.3	V
High-level output	Іон	1 pin			-8	mA
current		Total of P00-P0	1, P20-P27, P50-P57,	and P70-P73	-15	mA
		Total of P02-P0	7, P30-P37, P40-P47,	P60-P67,	-15	mA
		P74-P77, and P	120-P124			
		Total of P100-P	102		-10	mA
Low-level output	IOL Note 2	1 pin	pin Peak		16	mA
current				r.m.s	8	mA
		Total of P00-P0	1, P20-P27, P50-P57,	Peak value	30	mA
		and P70-P73		r.m.s	15	mA
		Total of P02-P0	7, P30-P37, P40-P47,	Peak value	30	mA
		P60-P67, P74-P	77, P120-P124, and	r.m.s	15	mA
		P130-P137				
		Total of P100-10	02	Peak value	20	mA
				r.m.s	10	mA
Operating temperature	TA	During normal o	peration		-40 to +85	°C
	During flash memory programming			10 to 40	°C	
Storage temperature	T _{stg}				-55 to +125	°C

Notes 1. Keep the voltage at VDDPORT, AVDD, and VDDPLL same as that at the VDD pin.

2. Calculate the r.m.s as follows: [r.m.s] = [Peak value] $x \sqrt{Duty}$

Caution If the rated value of even one of the above parameters is exceeded even momentarily, the quality of the product may be degraded. The absolute maximum ratings, therefore, are the values exceeding which the product may be physically damaged. Be sure to use the product with these ratings never being exceeded.

Remark Unless otherwise specified, the characteristics of a multiplexed pin are the same as those of the corresponding port pin.



Recommended Supply Voltage Ranges ($T_A = -40 \text{ to } +85^{\circ}\text{C}$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Supply voltage	V _{DD1}	When CPU and PLL are operating		5.0	5.5	٧
	V _{DD2}	When CPU is operating and PLL is stopped	3.5	5.0	5.5	V
Data retention voltage	V _{DDR}	When crystal oscillation stops	2.3		5.5	V
Output breakdown	V _{BDS}	P130-P137 (N-ch open drain)			15	V
voltage						

DC Characteristics (T_A = -40 to +85°C, V_{DD} = 3.5 to 5.5 V)

Parameter	Symbol	Test Cond	MIN.	TYP.	MAX.	Unit	
High-level input voltage	VIH1	P10-P17, P21, P23, P30, P3 P50-P57, P60-P67, P71, P73 P120, P122-P124		0.7 VDD		V _{DD}	V
	V _{IH2}	P00-P07, P20, P22, P24-P2 P74, P121, RESET	7, P32-P35, P70, P72,	0.8 V _{DD}		V _{DD}	V
Low-level input voltage	VIL1	P10-P17, P21, P23, P30, P3 P50-P57, P60-P67, P71, P73 P120, P122-P124		0		0.3 V _{DD}	V
	V _{IL2}	P00-P07, P20, P22, P24-P2 P74, P121, RESET	0		0.2 V _{DD}	V	
High-level output voltage	V _{OH1}	P00-P07, P20-P24, P30-P37, P40-P47, P50-P57, P60-P67,		V _{DD} - 1.0			V
		P70-P77, P100-P102, P120-P124	$3.5 \text{ V} \le \text{V}_{DD} < 4.5 \text{ V},$ Iон = -100 μ A	V _{DD} - 0.5			V
	V _{OH2}	EO0, EO1	$V_{DD} = 4.5 \text{ to } 5.5 \text{ V},$ $I_{OH} = -3 \text{ mA}$	V _{DD} - 1.0			V
Low-level output voltage	P ²	P00-P07, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67,	•			1.0	V
		P70-P77, P100-P102, P120-P124, P130-P137,	$3.5 \text{ V} \leq \text{V}_{DD} < 4.5 \text{ V},$ $\text{IoL} = 100 \ \mu\text{A}$			0.5	V
	V _{OL2}	EO0, EO1	V _{DD} = 4.5 to 5.5 V, I _{OL} = 3 mA			1.0	V
High-level input leakage current	Ісін	P00-P07, P10-P17, P20-P24, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P100-P102, P120-P124, RESET	Vi = Vdd			3	μΑ

Remark Unless otherwise specified, the characteristics of a multiplexed pin are the same as those of the corresponding port pin.

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DC Characteristics (T_A = -40 to +85°C, V_{DD} = 3.5 to 5.5 V)

Parameter	Symbol	Condit	ions	MIN.	TYP.	MAX.	Unit
Low-level input leakage current	luu	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P100-P102, P120-P124, RESET	V1 = 0 V			-3	μΑ
Output off	1 LOH1	P130-P137	Vo = 15 V			-3	μΑ
leakage current	ILOL1	P130-P137	Vo = 0 V			3	μΑ
	1ьон2	P25-P27 (at N-ch open drain I/O)	Vo = VDD			-3	μΑ
	ILOL2	P25-P27 (at N-ch open drain I/O)	Vo = 0 V			3	μΑ
	Ісонз	EO0, EO1	Vo = VDD			-3	μΑ
	Ісов	EO0, EO1	Vo = 0 V			3	μΑ
Supply current ^{Note}	I _{DD1}	When CPU is operating and PLL is stopped.	fx = 4.5 MHz		5.0	18	mA
	I _{DD2}	Sine wave input to X1 pin V _I = V _{DD}	fx = 6.3 MHz		7.0	20	mA
	I _{DD3}	In HALT mode with PLL stopped.	fx = 4.5 MHz		0.3	0.8	mA
	I _{DD4}	Sine wave input to X1 pin $V_1 = V_{DD}$	fx = 6.3 MHz		0.4	1.0	mA
Data retention	V _{DDR1}	When crystal resonator is o	scillating	3.5		5.5	V
voltage	V _{DDR2}	When crystal oscillation is stopped	Power-failure detection function	2.2			V
	V _{DDR3}		Data memory retained	2.0			V
Data retention current	IDDR1	When crystal oscillation is stopped	T _A = 25°C, V _{DD} = 5 V		2.0	4.0	μΑ
	IDDR2				2.0	20	μΑ

Note Excluding AVDD current and VDDPLL current.

Remarks 1. fx: System clock oscillation frequency

2. Unless otherwise specified, the characteristics of a multiplexed pin are the same as those of the corresponding port pin.



Reference Characteristics ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = 4.5 \text{ to } 5.5 \text{ V}$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Supply current	I _{DD5}	When CPU and PLL are operating.		8		mA
		Sine wave input to VCOH pin				
		At fin = 160 MHz, Vin = 0.15 V _{P-P}				

AC Characteristics

(1) Basic operation ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = 3.5 \text{ to } 5.5 \text{ V}$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Cycle time	Тсч	At $fx = 6.3 \text{ MHz}$	0.32		5.08	μs
(minimum instruction execution time)		At $fx = 4.5 \text{ MHz}^{\text{Note 1}}$	0.44		7.11	μs
TI00, TI01 input high-/low-level widths	tтіно, tтіLo		4/fsam ^{Note 2}			S
TI50, TI51 input frequency	fтıs				2	MHz
TI50, TI51 input high-/low-level widths	tтін5, tтіL5		200			ns
Interrupt input high-/low-level widths	tinth,	INTP0-INTP7	1			μs
RESET pin low-level width	trsL		10			μs

Notes 1. Only when products not using IEBus are supported.

2. $f_{sam} = f_x/2$, $f_x/4$, $f_x/64$ selectable by bits 0 and 1 (PRM00 and PRM01) of the prescaler mode register 0 (PRM0). However, $f_{sam} = f_x/8$ when the valid edge of TI00 is selected as the count clock.



(2) Serial interface ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = 3.5 \text{ to } 5.5 \text{ V}$)

(a) Serial interface 0

(i) 3-wire serial I/O mode (SCKO ... internal clock output)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
SCK0 cycle time	tkcy1	V _{DD} = 4.5 to 5.5 V	800			ns
			1600			ns
SCK0 high-/low-level width	tкн1,	V _{DD} = 4.5 to 5.5 V	tксү1/2 — 50			ns
	t _{KL1}		tkcy1/2 - 100			ns
SI0 setup time (to SCK0↑)	tsıĸı	V _{DD} = 4.5 to 5.5 V	100			ns
			150			ns
SI0 hold time (from SCK0↑)	tksi1		400			ns
SO0 output delay time from SCK0↓	tkso1	C = 100 pF Note			300	ns

Note C is the load capacitance of SCK0 and SO0 output line.

(ii) 3-wire serial I/O mode (SCK0 ... external clock input)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
SCK0 cycle time	tkcy2	V _{DD} = 4.5 to 5.5 V	800			ns
			1600			ns
SCK0 high-/low-level width	tĸH2,	V _{DD} = 4.5 to 5.5 V	400			ns
	tĸL2		800			ns
SI0 setup time (to SCK0↑)	tsık2		100			ns
SI0 hold time (from SCK0↑)	tksi2		400			ns
SO0 output delay time from SCK0↓	tkso2	C = 100 pF Note			300	ns
SCK0 at rising or falling edge time	tr2, tr2				1000	ns

Note C is the load capacitance of SO0 output line.



(iii) SBI mode (SCK0 ... internal clock output)

Parameter	Symbol	Test (Conditions	MIN.	TYP.	MAX.	Unit
SCK0 cycle time	tксүз	$V_{DD} = 4.5 \text{ to } 5.0$.5 V	800			ns
				3200			ns
SCK0 high-/low-level width	t кнз,	V _{DD} = 4.5 to 5.5 V		tксүз/2 – 50			ns
	tкLз		tĸ				ns
SB0, SB1 setup time (to SCK0↑)	tsıкз	V _{DD} = 4.5 to 5.	.5 V	100			ns
				300			ns
SB0, SB1 hold time (from SCK0↑)	t ksi3			tксүз/2			ns
SB0, SB1 output delay time from	tкsоз	R = 1 kΩ	V _{DD} = 4.5 to 5.5 V	0		250	ns
SCK0↓		C = 100 pF Note		0		1000	ns
SB0, SB1↓ from SCK0↑	tкsв			tксүз			ns
SCK0↓ from SB0, SB1↓	tsвк			tксүз			ns
SB0, SB1 high-level width	tsвн			tксүз			ns
SB0, SB1 low-level width	t sBL			tксүз			ns

 $\textbf{Note} \quad \text{R and C are the load resistance and load capacitance of } \overline{\text{SCK0}}, \, \text{SB0 and SB1 output line}.$

(iv) SBI mode (SCK0 ... external clock input)

Parameter	Symbol	Test (Conditions	MIN.	TYP.	MAX.	Unit
SCK0 cycle time	tkcy4	V _{DD} = 4.5 to 5.	.5 V	800			ns
				3200			ns
SCK0 high-/low-level width	tĸH4,	V _{DD} = 4.5 to 5.	.5 V	400			ns
	tĸL4						ns
SB0, SB1 setup time (to SCK0↑)	tsık4	V _{DD} = 4.5 to 5.	V _{DD} = 4.5 to 5.5 V				ns
				300			ns
SB0, SB1 hold time (from SCK0↑)	tksi4			tkcy4/2			ns
SB0, SB1 output delay time from	t KSO4	R = 1 kΩ	$V_{DD} = 4.5 \text{ to } 5.5 \text{ V}$	0		250	ns
SCK0↓		C = 100 pF Note		0		1000	ns
SB0, SB1↓ from SCK0↑	tкsв			tKCY4			ns
SCK0↓ from SB0, SB1↓	tsвк			tKCY4			ns
SB0, SB1 high-level width	tsвн			tKCY4			ns
SB0, SB1 low-level width	tsbl			tKCY4			ns
SCK0 at rising or falling edge time	tr4, tr4					1000	ns

Note R and C are the load resistance and load capacitance of SB0 and SB1 output line.

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(v) 2-wire serial I/O mode (SCK0 ... internal clock output)

Parameter	Symbol	Test	Conditions	MIN.	TYP.	MAX.	Unit
SCK0 cycle time	tkcy5	R = 1 kΩ		1600			ns
SCK0 high-level width	t KH5	C = 100 pF Note		tксү5/2 – 160			ns
SCK0 low-level width	tĸL5		V _{DD} = 4.5 to 5.5 V	tксу5/2 — 50			ns
				tксу5/2 — 100			ns
SB0, SB1 setup time (to SCK0↑)	tsık5		V _{DD} = 4.5 to 5.5 V	300			ns
				350			ns
SB0, SB1 hold time (from SCK0↑)	tksi5			600			ns
$\begin{array}{ c c c }\hline SB0, SB1 \text{ output delay time from}\\ \hline \overline{SCK0} \downarrow \end{array}$	tkso5			0		300	ns

Note R and C are the load resistance and load capacitance of SCK0, SB0 and SB1 output line.

(vi) 2-wire serial I/O mode (SCKO ... external clock input)

Parameter	Symbol	Test Conditions		MIN.	TYP.	MAX.	Unit
SCK0 cycle time	tkcy6			1600			ns
SCK0 high-level width	t кн6			650			ns
SCK0 low-level width	tĸL6			800			ns
SB0, SB1 setup time (to SCK0↑)	tsik6			100			ns
SB0, SB1 hold time (from SCK0↑)	tksi6			tkcy6/2			ns
SB0, SB1 output delay time from	t KSO6	R = 1 kΩ	V _{DD} = 4.5 to 5.5 V	0		300	ns
SCK0↓		C = 100 pF Note		0		500	ns
SCK0 at rising or falling edge time	tre, tre					1000	ns

Note R and C are the load resistance and load capacitance of SB0 and SB1 output line.



(vii) I²C Bus mode (SCL ... internal clock output)

Parameter	Symbol	Test	Conditions	MIN.	TYP.	MAX.	Unit
SCL cycle time	tkcy7	R = 1 kΩ		10			μs
SCL high-level width	t кн7	C = 100 pF Note		tксүт – 160			ns
SCL low-level width	t _{KL7}			tксүү — 50			ns
SDA0, SDA1 setup time (to SCL↑)	tsık7			200			ns
SDA0, SDA1 hold time (from SCL↓)	tksi7			0			ns
SDA0, SDA1 output delay time	t KS07		V _{DD} = 4.5 to 5.5 V	0		300	ns
(from SCL↓)				0		500	ns
SDA0, SDA1↓ from SCL↑ or SDA0, SDA1↑ from SCL↑	tкsв			200			ns
SCL↓ from SDA0, SDA1↓	tsвк			400			ns
SDA0, SDA1 high-level width	tsвн			500			ns

Note R and C are the load resistance and load capacitance of SCL, SDA0 and SDA1 output line.

(viii) I²C Bus mode (SCL ... external clock input)

Parameter	Symbol	Test	Conditions	MIN.	TYP.	MAX.	Unit
SCL cycle time	tkcy8			1000			ns
SCL high-/low-level width	t KH8, t KL8			400			ns
SDA0, SDA1 setup time (to SCL↑)	tsık8			200			ns
SDA0, SDA1 hold time (from SCL↓)	tksi8			0			ns
SDA0, SDA1 output delay time	tkso8	R = 1 kΩ	V _{DD} = 4.5 to 5.5 V	0		300	ns
from SCL↓		C = 100 pF Note		0		500	ns
SDA0, SDA1↓ from SCL↑ or SDA0, SDA1↑ from SCL↑	tкsв			200			ns
SCL↓ from SDA0, SDA1↓	tsвк			400			ns
SDA0, SDA1 high-level width	tsвн			500			ns
SCL at rising or falling edge time	trs, trs					1000	ns

Note R and C are the load resistance and load capacitance of SDA0 and SDA1 output line.

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(b) Serial interface 1

(i) 3-wire serial I/O mode (SCK1 ... internal clock output)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
SCK1 cycle time	tkCY9		800			ns
SCK1 high/low-level width	tкн9, tкL9		tксү9/2 – 50			ns
SI1 setup time (to SCK1↑)	tsik9		100			ns
SI1 hold time (from SCK1↑)	tksi9		400			ns
SO1 output delay time (from SCK1↓)	t KSO9	C = 100 pF Note			300	ns

Note $\,$ C is the load capacitance of $\overline{\text{SCK1}}$ and SO1 output line.

(ii) 3-wire serial I/O mode (SCK1 ... external clock input)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
SCK1 cycle time	tKCY10		800			ns
SCK1 high/low-level width	t кн10,		400			ns
	t KL10					
SI1 setup time (to SCK1↑)	tsiĸ10		100			ns
SI1 hold time (from SCK1↑)	tksi10		400			ns
SO1 output delay time (from SCK1↓)	t KSO10	C = 100 pF Note			300	ns
SCK1 at rising or falling edge time	tr10, tr10				1000	ns

Note C is the load capacitance of SO1 output line.



(iii) 3-wire serial I/O mode with automatic transmit/receive function (SCK1 ... internal clock output)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
SCK1 cycle time	tkcy11		800			ns
SCK1 high/low-level width	tкн11, tкL11		tkcy11/2 - 50			ns
SI1 setup time (to SCK1↑)	tsıĸ11		100			ns
SI1 hold time (from SCK1↑)	tksi11		400			ns
SO1 output delay time (from SCK1↓)	t KSO11	C = 100 pF Note			300	ns
STB↑ from SCK1↑	tsbd		tксү11/2 - 100		tксү11/2 + 100	ns
Strobe signal high-level width	tssw		tксү11/2 - 30		tkcy11/2 + 30	ns
Busy signal setup time (to busy signal detection timing)	t _{BYS}		100			ns
Busy signal hold time (from busy signal detection timing)	tвүн		100			ns
SCK1↓ from busy inactive	tsps		200			ns

Note C is the load capacitance of SO1 output line.

(iv) 3-wire serial I/O mode with automatic transmit/receive function (SCK1 ... external clock input)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
SCK1 cycle time	tKCY12		800			ns
SCK1 high/low-level width	t KH12,		400			ns
	t KL12					
SI1 setup time (to SCK1↑)	tsik12		100			ns
SI1 hold time (from SCK1↑)	tksi12		400			ns
SO1 output delay time (from SCK1↓)	t KSO12	C = 100 pF Note			300	ns
SCK1 at rising or falling edge time	t _{R12} , t _{F12}				1000	ns

Note C is the load capacitance of SO1 output line.



(c) Serial interface 3

(i) 3-wire serial I/O mode (SCK3 ... internal clock output)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
SCK3 cycle time	t KCY13		800			ns
SCK3 high/low-level width	tкн13, tкL13		tксү13/2 — 50			ns
SI3 setup time (to SCK3↑)	tsıк13		100			ns
SI3 hold time (from SCK3↑)	tksi13		400			ns
SO3 output delay time (from SCK3↓)	t KSO13	C = 100 pF Note			300	ns

Note C is the load capacitance of SCK3 and SO3 output line.

(ii) 3-wire serial I/O mode (SCK3 ... external clock input)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
SCK3 cycle time	tKCY14		800			ns
SCK3 high/low-level width	t KH14,		400			ns
	tKL14					
SI3 setup time (to SCK31)	tsik14		100			ns
SI3 hold time (from SCK3↑)	tksi14		400			ns
SO3 output delay time (from SCK3↓)	t KSO14	C = 100 pF Note			300	ns
SCK3 at rising or falling edge time	t _{R14} , t _{F14}				1000	ns

Note C is the load capacitance of SO3 output line.

(d) Serial interface UARTO (Dedicated baud rate generator output)

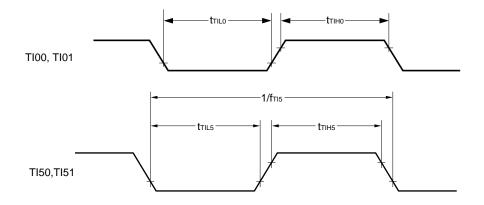
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate					38400	bps



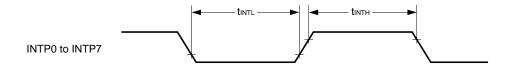
AC Timing Test Point (Excluding X1 Input)



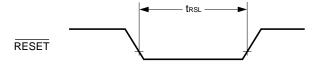
TI Timing



Interrupt Input Timing



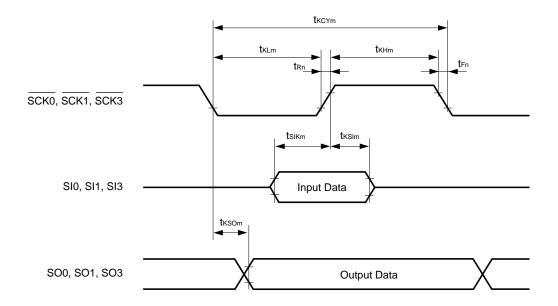
RESET Input Timing





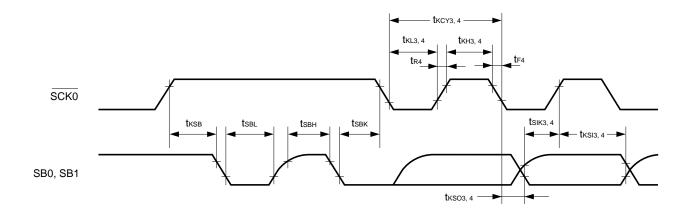
Serial Transfer Timing

3-wire serial I/O mode:

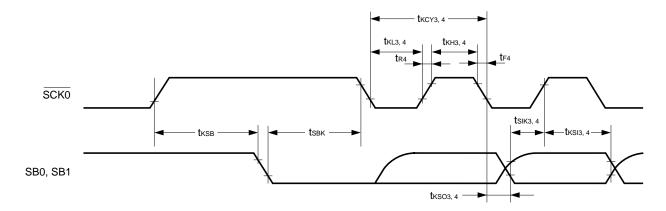


Remark m = 1, 2, 9, 10, 13, 14n = 2, 10, 14

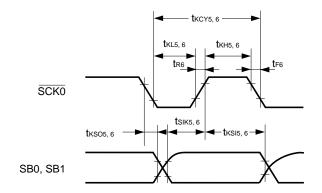
SBI mode (bus release signal transfer):



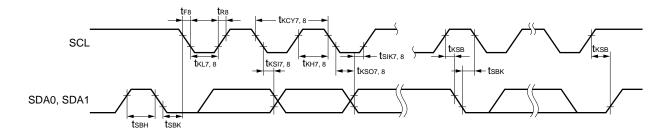
SBI mode (command signal transfer):



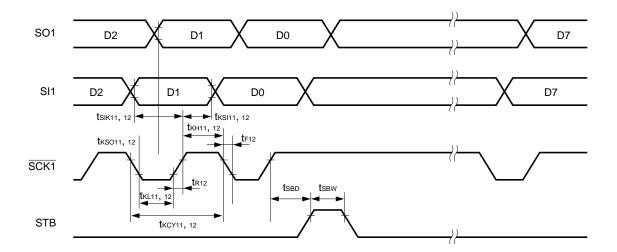
2-wire serial I/O mode:



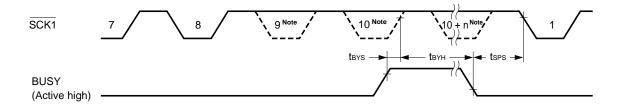
I²C bus mode:



3-wire serial I/O mode with automatic transmit/receive function:



3-wire serial I/O mode with automatic transmit/receive function (busy processing):



Note The signal is not actually driven low here; it is shown as such to indicate the timing.

IEBus Controller Characteristics ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = 3.5 \text{ to } 5.5 \text{ V}$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
IEBus system clock frequency	fs	Fixed to mode 1		6.3 ^{Note}		MHz

Note Although the system clock frequency is 6.0 MHz in the IEBus standard, in these products, normal operation is guaranteed at 6.3 MHz.

Remark 6.0 MHz and 6.3 MHz cannot both be used as the IEBus system clock frequency.



A/D Converter Characteristics ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = AV_{DD} = 3.5 \text{ to } 5.5 \text{ V}$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution			8	8	8	bit
Total conversion		V _{DD} = 4.5 to 5.5 V			±1.0	%FSR
errorNotes 1, 2					±1.4	%FSR
Conversion time	tconv		15.2		45.7	μs
Analog input voltage	VIAN		0		V _{DD}	V

- **Notes 1.** Excluding quantization error (±0.2%FSR)
 - 2. This value is indicated as a ratio to the full-scall value.

PLL Characteristics ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = 4.5 \text{ to } 5.5 \text{ V}$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating	f _{IN1}	VCOL pin, MF mode, sine wave input, $V_{IN} = 0.15 \text{ V}_{P-P}$	0.5		3.0	MHz
frequency	f _{IN2}	VCOL pin, HF mode, sine wave input, V _{IN} = 0.15 V _{P-P}	10		40	MHz
	fınз	VCOH pin, VHF mode, sine wave input, $V_{\text{IN}} = 0.15 \text{ V}_{\text{P-P}}$	60		130	MHz
	fin4	VCOH pin, VHF mode, sine wave input, $V_{\text{IN}} = 0.3 \text{ V}_{\text{P-P}}$	40		160	MHz

Remark The above values are the result of NEC's evaluation of the device. If the device is likely to be affected by noise in your application, it is recommended to use the device at a voltage higher than the above values.

IFC Characteristics (T_A = -40 to +85°C, V_{DD} = 4.5 to 5.5 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating frequency	fin5	AMIFC pin, AMIF count mode, sine wave input, $V_{\text{IN}} = 0.15 \ V_{\text{P-P}}$	0.4		0.5	MHz
	fin6	FMIFC pin, FMIF count mode, sine wave input, V _{IN} = 0.15 V _{P-P}	10		11	MHz
	f _{IN7}	FMIFC pin, AMIF count mode, sine wave input, $V_{\text{IN}} = 0.15 \ V_{\text{P-P}}$	0.4		0.5	MHz

Remark The above values are the result of NEC's evaluation of the device. If the device is likely to be affected by noise in your application, it is recommended to use the device at a voltage higher than the above values.



Flash Memory Programming Characteristics (V_{DD} = 3.5 to 5.5 V, T_A = 10 to 40°C)

(1) Write/delete characteristics

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Write current (VDD pin)Note	toow	When VPP = VPP1, fx = 6.3 MHz			23	mA
Write current (VPP pin)Note	IPPW	When VPP = VPP1, fx = 6.3 MHz			20	mA
Delete current (VDD pin)Note	IDDE	When VPP = VPP1, fx = 6.3 MHz			23	mA
Delete current (VPP pin)Note	Ірре	When VPP = VPP1			100	mA
Unit delete time	ter		0.5	1	1	s
Total delete time	tera				20	s
Number of overwrite	Cwrt	Delete and write are counted as one cycle			20	times
VPP power supply voltage	V _{PP0}	In normal mode	0		0.2 V _{DD}	V
	V _{PP1}	At flash memory programming	9.7	10.0	10.3	V

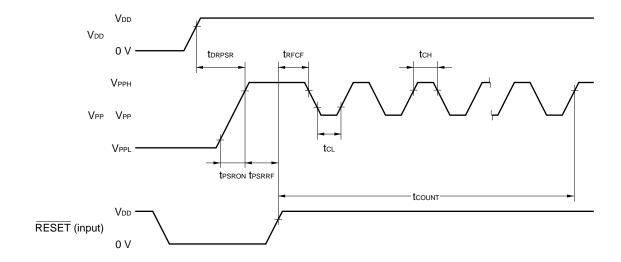
Note AVDD current and Port current (current flowing to internal pull-up resistor) are not included.

Remark fx: System clock oscillation frequency

(2) Serial write operation characteristics

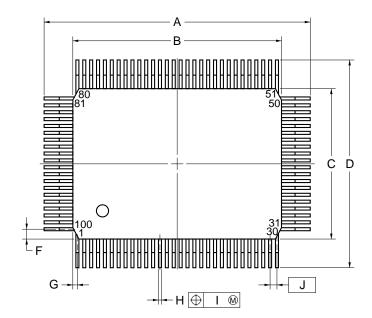
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
V _{PP} setup time	t PSRON	V _{PP} high voltage	1.0			μs
V _{PP} ↑ setup time from V _{DD} ↑	torpsr	V _{PP} high voltage	1.0			μs
RESET↑ setup time from V _{PP} ↑	t PSRRF	V _{PP} high voltage	1.0			μs
V _{PP} count start time from RESET↑	trfcf		1.0			μs
Count execution time	t COUNT				2.0	ms
VPP counter high-level width	tсн		8.0			μs
VPP counter low-level width	tcL		8.0			μs
V _{PP} counter noise elimination width	tnfw			40		ns

Flash Write Mode Setting Timing

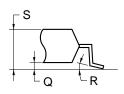


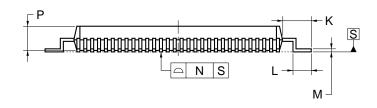
8. PACKAGE DRAWING

★ 100-PIN PLASTIC QFP (14x20)



detail of lead end





NOTE

Each lead centerline is located within 0.15 mm of its true position (T.P.) at maximum material condition.

MILLIMETERS
23.6±0.4
20.0±0.2
14.0±0.2
17.6±0.4
0.8
0.6
0.30±0.10
0.15
0.65 (T.P.)
1.8±0.2
0.8±0.2
$0.15^{+0.10}_{-0.05}$
0.10
2.7±0.1
0.1±0.1
5°±5°
3.0 MAX.

P100GF-65-3BA1-4

9. RECOMMENDED SOLDERING CONDITIONS

Solder this product under the following recommended conditions.

For details of the recommended soldering conditions, refer to information document **Semiconductor Device Mounting Technology Manual (C10535E)**.

For soldering methods and conditions other than those recommended, consult NEC.

Table 9-1. Soldering Conditions for Surface-Mount Type

 μ PD178F098GF-3BA: 100-pin plastic QFP (14 × 20)

Soldering Method	Soldering Conditions	Recommended Conditions Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 sec max. (210°C min.), Number of times: 3 max.	IR35-00-3
VPS	Package peak temperature: 215°C, Time: 40 sec max. (200°C min.), Number of times: 3 max.	VP15-00-3
Wave soldering	Solder bath temperature: 260°C max., Time: 10 sec max., Number of times: 1, Preheating temperature: 120°C max., (Package surface temperature)	WS60-00-1
Partial heating	Pin temperature: 300°C max., Time: 3 sec max (per device side)	_

Caution Do not use two or more soldering methods in combination (except partial heating).



* APPENDIX A. DEVELOPMENT TOOLS

The following development tools are available for development of systems using the μ PD178078 and 178098 subseries.

Language processor software

RA78K/0 ^{Notes} 1, 2, 3	Assembler package common to 78K/0 series
CC78K/0Notes 1, 2, 3	C compiler package common to 78K/0 series
DF178098Notes 1, 2, 3	Device file for μ PD178078 subseries and μ PD178098 subseries
CC78K0-LNotes 1, 2, 3	C compiler library source file common to 78K/0 series

Flash memory writing tools

Fashpro III	Dedicated flash programmer
(Part number: FL-PR3 ^{Note 4} , PG-FL3)	
FA-100GF-3BANote 4	Flash programmer adapter

Debugging tools

When in-circuit emulator IE-78K0-NS is used

IE-78K0-NS	In-circuit emulator common to 78K/0 series
IE-70000-MC-PS-B	Power supply unit for IE-78K0-NS
IE-78K0-NS-PA	Performance board for enhancing and expanding the IE-78K0-NS function
IE-70000-98-IF-C	Interface adapter necessary when PC-9800 series (except notebook type) is used as host machine (C bus supported)
IE-70000-CD-IF-A	PC card and interface cable necessary when a notebook-type PC is used as host machine (PCMCIA socket supported)
IE-70000-PC-IF-C	Interface adapter necessary when a IBM PC/AT TM compatible machine is used as host machine (ISA bus supported)
IE-70000-PCI-IF	Interface adapter necessary when a PC with a PCI bus is used as host machine
IE-178098-NS-EM1	Emulation board to emulate μ PD178078 and 178098 subseries
NP-100GF ^{Note 4}	Emulation probe for 100-pin plastic QFP (GF-3BA type)
EV-9200GF-100	Socket mounted on board of target system created for 100-pin plastic QFP (GF-3BA type)
SM78K0Notes 1, 2	System simulator common to 78K/0 series
ID78K0-NSNotes 1, 2	Integrated debugger common to 78K/0 series
DF178098Notes 1, 2, 3	Device file for μ PD178078 subseries and μ PD178098 subseries

- Notes 1. PC-9800 series (Japanese Windows™) based
 - 2. IBM PC/AT compatible machine (Japanese/English windows) based
 - 3. HP9000 series 700[™] (HP-UX[™]) based, SPARCstation[™] (SunOS[™], Solaris[™]) based, NEWS[™] (NEWS-OSTM) based
 - 4. Products of Naito Densei Machida Mfg. Co., Ltd. (Tel: 044-822-3813).

Remark Use the RA78K0, CC78K0, and SM78K0 in combination with the DF178098.

• When in-circuit emulator IE-78001-R-A is used

IE-78001-R-A	In-circuit emulator common to 78K/0 series
IE-70000-98-IF-C	Interface adapter necessary when PC-9800 series (except notebook type) is used as host machine (C bus supported)
IE-70000-PC-IF-C	Interface adapter necessary when IBM PC/AT compatible machine is used as host machine (ISA bus supported)
IE-70000-PCI-IF	Interface adapter necessary when a PC with a PCI bus is used as host machine
IE-78000-R-SV3	Interface adapter and cable necessary when EWS is used as host machine
IE-178098-NS-EM1	Emulation board to emulate μ PD178078 and 178098 subseries
IE-78K0-R-EX1	Emulation probe conversion board necessary when using IE-178098-NS-EM1 on IE-78001-R-A
EP-78064GF-R	Emulation probe for 100-pin plastic QFP (GF-3BA type)
EV-9200GF-100	Socket mounted on board of target system created for 100-pin plastic QFP (GF-3BA type)
SM78K0Notes 1, 2	System simulator common to 78K/0 series
ID78K0 ^{Notes 1, 2}	Integrated debugger common to 78K/0 series
DF178098Notes 1, 2, 3	Device file for μ PD178078 subseries and μ PD178098 subseries

Real-time OS

RX78K/0 ^{Notes 1, 2, 3}	Real-time OS for 78K/0 series
MX78K0Notes 1, 2, 3	OS for 78K/0 series

Notes 1. PC-9800 series (Japanese Windows) based

- 2. IBM PC/AT compatible machine (Japanese/English windows) based
- 3. HP9000 series 700 (HP-UX) based, SPARCstation (SunOS, Solaris) based, NEWS (NEWS-OS) based

Remark Use the SM78K0 in combination with the DF178098.



* APPENDIX B. RELATED DOCUMENTS

The related documents indicated in this publication may include preliminary versions. However, preliminary versions are not marked as such.

Device Documents

Title .		Document No.	
		Japanese	English
μPD178076, 178078, 178096, 178098 Data Sheet		U12885J	U12885E
μPD178F098 Data Sheet		U12920J	This document
μPD178078, 178098 Subseries User's Manual		U12790J	U12790E
78K/0 Series User's Manual - Instruction		U12326J	U12326E
78K/0 Series Application Note	Basics (I)	U12704J	U12704E
78K/0, 78K/0S Series Flash Memory Write Application Note		U14458J	U14458E

Development Tool Documents (User's Manual)

Title		Document No.	
		Japanese	English
RA78K0 Assembler Package	Operation	U11802J	U11802E
	Assembly Language	U11801J	U11801E
	Structured Assembly	U11789J	U11789E
	Language		
CC78K0 C Compiler	Operation	U11517J	U11517E
	Language	U11518J	U11518E
IE-78001-R-A		U14142J	To be prepared
IE-78K0-NS		U13731J	U13731E
IE-178098-NS-EM1		U14013J	U14013E
EP-78064		EEU-934	EEU-1469
SM78K0 System Simulator Windows Based	Reference	U10181J	U10181E
SM78K Series System Simulator	External Parts User Open Interface Specifications	U10092J	U10092E
ID78K0 Integrated Debugger EWS Based	Reference	U11151J	_
ID78K0 Integrated Debugger PC Based	Reference	U11539J	U11539E
ID78K0 Integrated Debugger Windows Based	Guide	U11649J	U11649E
ID78K0-NS Integrated Debugger Windows Based	Reference	U12900J	U12900E
	Operation	U14379J	To be prepared

Caution The contents of the above documents are subject to change without notice. Please ensure that the latest versions are used in design work, etc.

Related Documents for Embedded Software (User's Manual)

Title		Document No.	
		Japanese	English
78K/0 Series Real-time OS	Fundamental	U11537J	U11537E
	Installation	U11536J	U11536E
78K/0 Series OS MX78K0	Fundamental	U12257J	U12257E

Other Documents

Title	Document No.	
Title	Japanese	English
SEMICONDUCTOR SELECTION GUIDE Products & Packages (CD-ROM)	X13769X	
Semiconductor Device Mounting Technology Manual	C10535J	C10535E
Quality Guides on NEC Semiconductor Devices	C11531J	C11531E
NEC Semiconductor Device Reliability and Quality Control	C10983J	C10983E
Guide to Prevent Damage for Semiconductor Devices by Electrostatic Discharge (ESD)	C11892J	C11892E
Semiconductor Device Quality/Reliability Handbook	C12769J	_
Microcomputer Product Series Guide	U11416J	_

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NOTES FOR CMOS DEVICES -

1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

② HANDLING OF UNUSED INPUT PINS FOR CMOS

Note:

No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

(3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note:

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

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- Network requirements

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Scandinavia Office Taeby, Sweden Tel: 08-63 80 820 Fax: 08-63 80 388

NEC Electronics Hong Kong Ltd.

Hong Kong Tel: 2886-9318 Fax: 2886-9022/9044

NEC Electronics Hong Kong Ltd.

Seoul Branch Seoul, Korea Tel: 02-528-0303 Fax: 02-528-4411

NEC Electronics Singapore Pte. Ltd.

United Square, Singapore 1130 Tel: 65-253-8311 Fax: 65-250-3583

NEC Electronics Taiwan Ltd.

Taipei, Taiwan Tel: 02-2719-2377 Fax: 02-2719-5951

NEC do Brasil S.A.

Electron Devices Division Rodovia Presidente Dutra, Km 214 07210-902-Guarulhos-SP Brasil

Tel: 55-11-6465-6810 Fax: 55-11-6465-6829

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